
1SS286

Silicon Schottky Barrier Diode for Various Detector,
High Speed Switching

HITACHI

ADE-208-302A (Z)

Rev. 1
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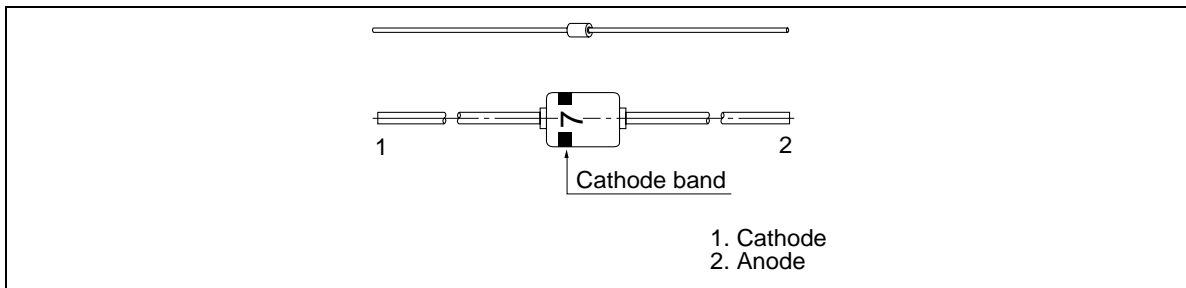
Features

- Very low reverse current.
- Detection efficiency is very good.
- Small glass package (MHD) enables easy mounting and high reliability.

Ordering Information

Type No.	Cathode band	Mark	Package Code
1SS286	Green	7	MHD

Outline



1SS286

Absolute Maximum Ratings

(Ta = 25°C)

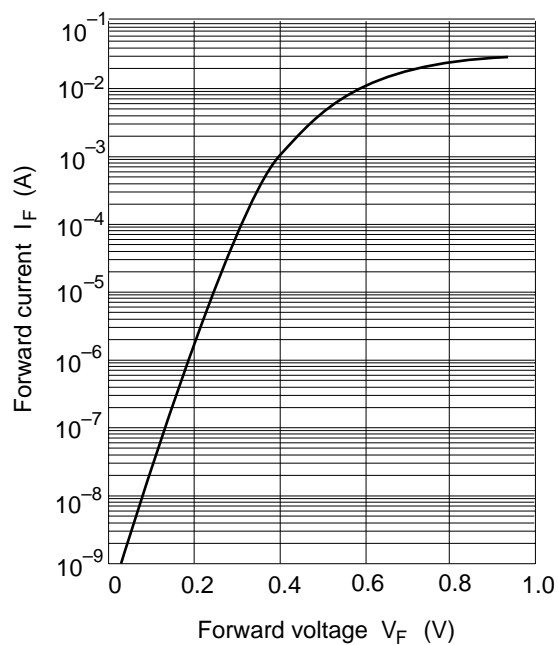
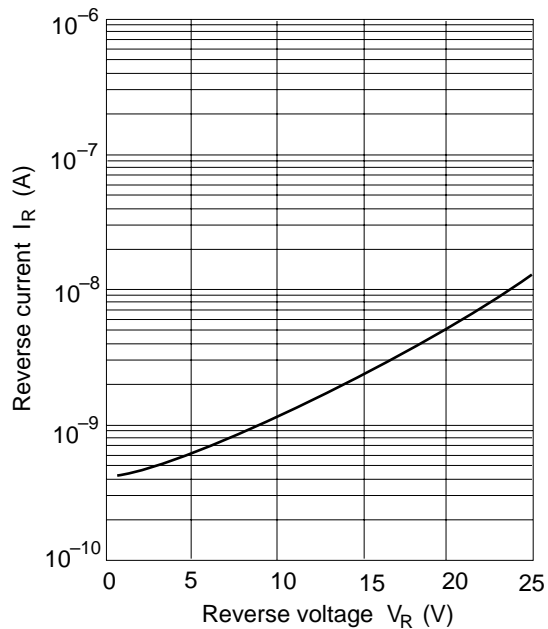
Item	Symbol	Value	Unit
Reverse voltage	V_R	25	V
Forward current	I_F	35	mA
Power dissipation	P_d	150	mW
Junction temperature	T_j	100	°C
Storage temperature	T_{stg}	-55 to +100	°C

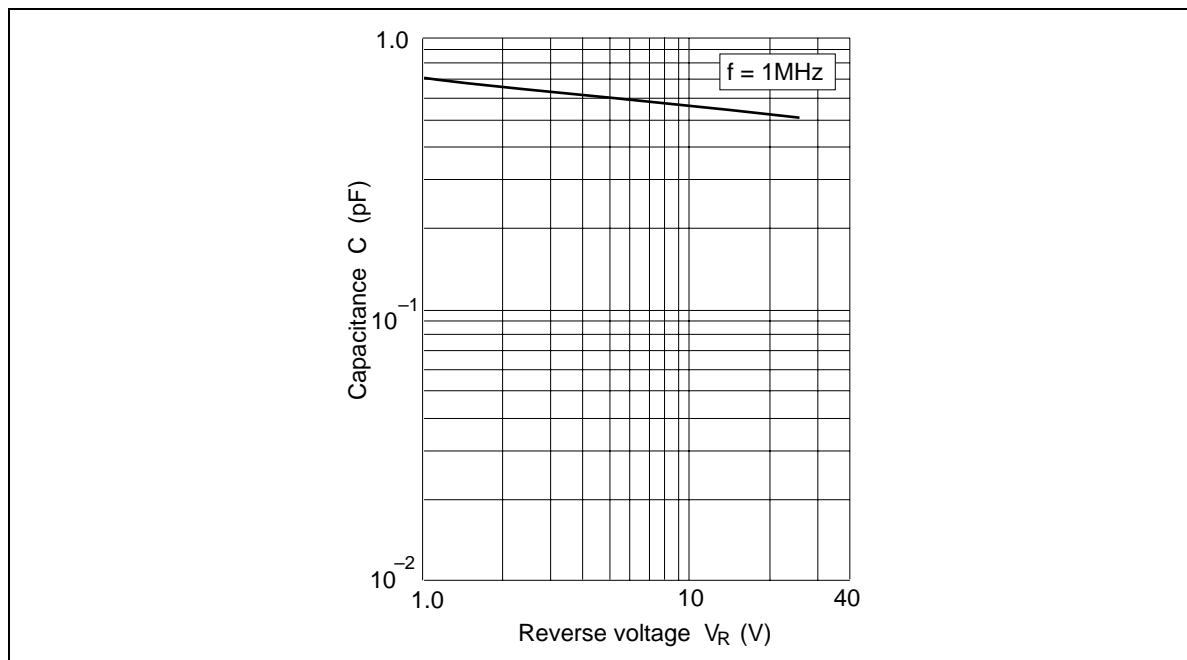
Electrical Characteristics

(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Forward voltage	V_F	—	—	0.6	V	$I_F = 10\text{mA}$
Reverse voltage	V_R	25	—	—	V	$I_R = 10\mu\text{A}$
Reverse current	I_R	—	—	10	nA	$V_R = 10\text{V}$
Capacitance	C	—	—	1.2	pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$
Capacitance deviation	ΔC	—	—	0.1	pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$
Forward voltage deviation	ΔV_F	—	—	10	mV	$I_F = 10\text{mA}$
ESD-Capability	—	10	—	—	V	*1C = 200pF, Both forward and reverse direction 1 pulse.

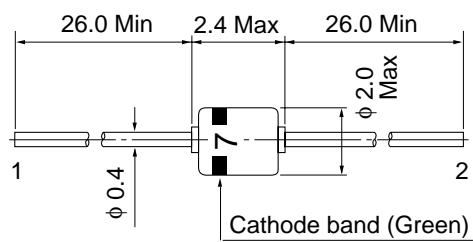
Notes: 1. Failure criterion; $I_R \geq 20\mu\text{A}$
2. Each group shall unify a multiple of 4 diodes

**Fig.1 Forward current Vs. Forward voltage****Fig.2 Reverse current Vs. Reverse voltage**

**Fig.3 Capacitance Vs. Reverse voltage**

Package Dimensions

Unit: mm



1 Cathode
2 Anode

HITACHI Code	MHD
JEDEC Code	DO-34
EIAJ Code	—
Weight (g)	0.084

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Sales Offices

HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: (03) 3270-2111 Fax: (03) 3270-5109

URL	NorthAmerica	: http://semiconductor.hitachi.com/
	Europe	: http://www.hitachi-eu.com/hel/ecg
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For further information write to:

Hitachi Semiconductor (America) Inc.	Hitachi Europe Ltd.
179 East Tasman Drive	Electronic Components Group
San Jose, CA 95134	Whitebrook Park
Tel: <1> (408) 433-1990	Lower Cookham Road
Fax: <1> (408) 433-0223	Maidenhead
	Berkshire SL6 8YA, United Kingdom
	Tel: <44> (1628) 585000
	Fax: <44> (1628) 585200

Hitachi Europe GmbH
Electronic Components Group
Dornacher Straße 3
D-85622 Feldkirchen, Munich
Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9 29 30 00

Hitachi Asia Ltd.
Hitachi Tower
16 Collyer Quay #20-00
Singapore 049318
Tel: <65>-538-6533/538-8577
Fax: <65>-538-6933/538-3877
URL: http://www.hitachi.com.sg

Hitachi Asia Ltd.
(Taipei Branch Office)
4/F, No. 167, Tun Hwa North Road
Hung-Kuo Building
Taipei (105), Taiwan
Tel: <886>-(2)-2718-3666
Fax: <886>-(2)-2718-8180
Telex: 23222 HAS-TP
URL: http://www.hitachi.com.tw

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower
World Finance Centre,
Harbour City, Canton Road
Tsim Sha Tsui, Kowloon
Hong Kong
Tel: <852>-(2)-735-9218
Fax: <852>-(2)-730-0281
URL: http://semiconductor.hitachi.com.hk

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